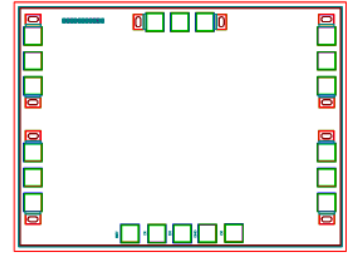


**AMT1705**  
**0 - 20GHz SP4T Switch Chip**



**Key Features :**

- Frequency range : 0 – 20GHz
- Insertion loss : 1.7dB
- Isolation : 50dB
- Input standing wave : 1.5
- Switch ON output standing wave : 1.4
- Switch OFF output standing wave : 1.2
- Switching time : 30ns
- Control method : TTL
- Chip dimensions : 2mm x 1.5mm x 0.1mm
- Applications : wireless communication, transceiver module, radio telecommunication etc.

**Description :**

AMT1705 is a high performance FET SP4T switch chip, it is designed by Gallium Arsenide (GaAs) pHEMT process. The chip uses -5V TTL level control, typical insertion loss is 1.7dB, isolation is 50dB, input standing wave 1.5. This chip is designed with ground through metal vias on the back technology. All chip products p are 100% RF tested.

**Absolute Maximum Ratings (Ta = 25°C)**

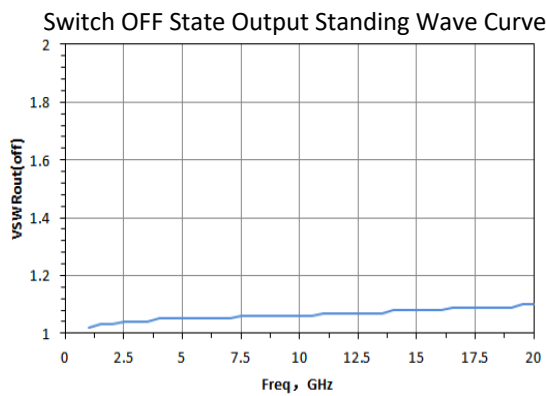
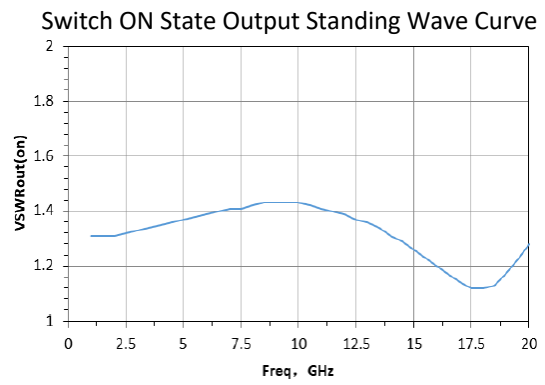
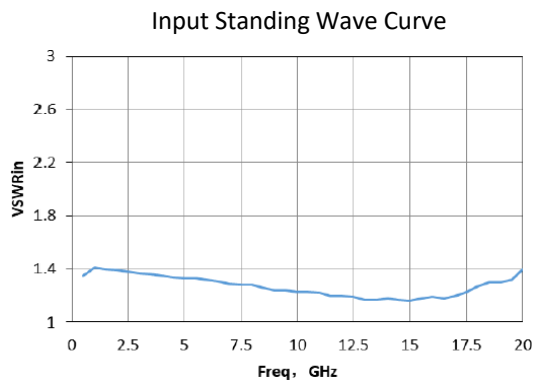
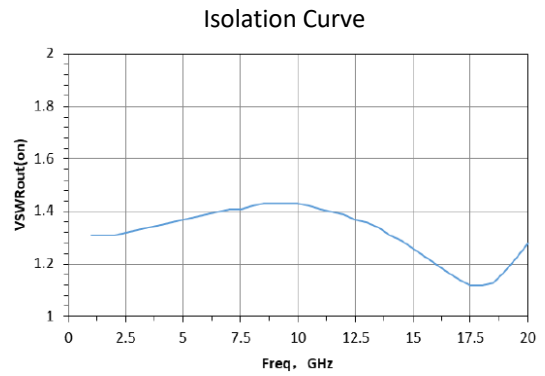
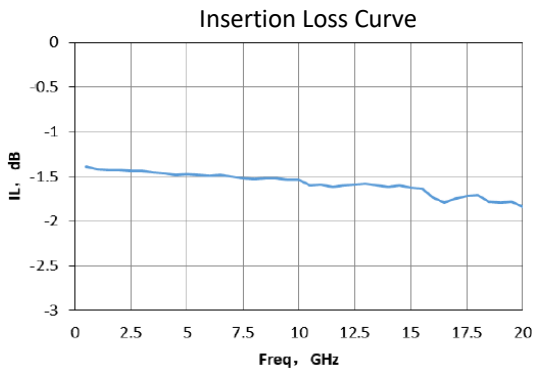
| Symbol | Parameter             | Value        | Remark                         |
|--------|-----------------------|--------------|--------------------------------|
| VSS    | Supply voltage        | -5V          |                                |
| Pin    | Input Power           | 30dBm        |                                |
| Tm     | Sintering Temperature | 310°C        | 30s, N <sub>2</sub> protection |
| Tstg   | Storage Temperature   | -65 ~ +150°C |                                |

[1] Operation outside any of the Absolute Maximum Ratings may cause permanent device damage.

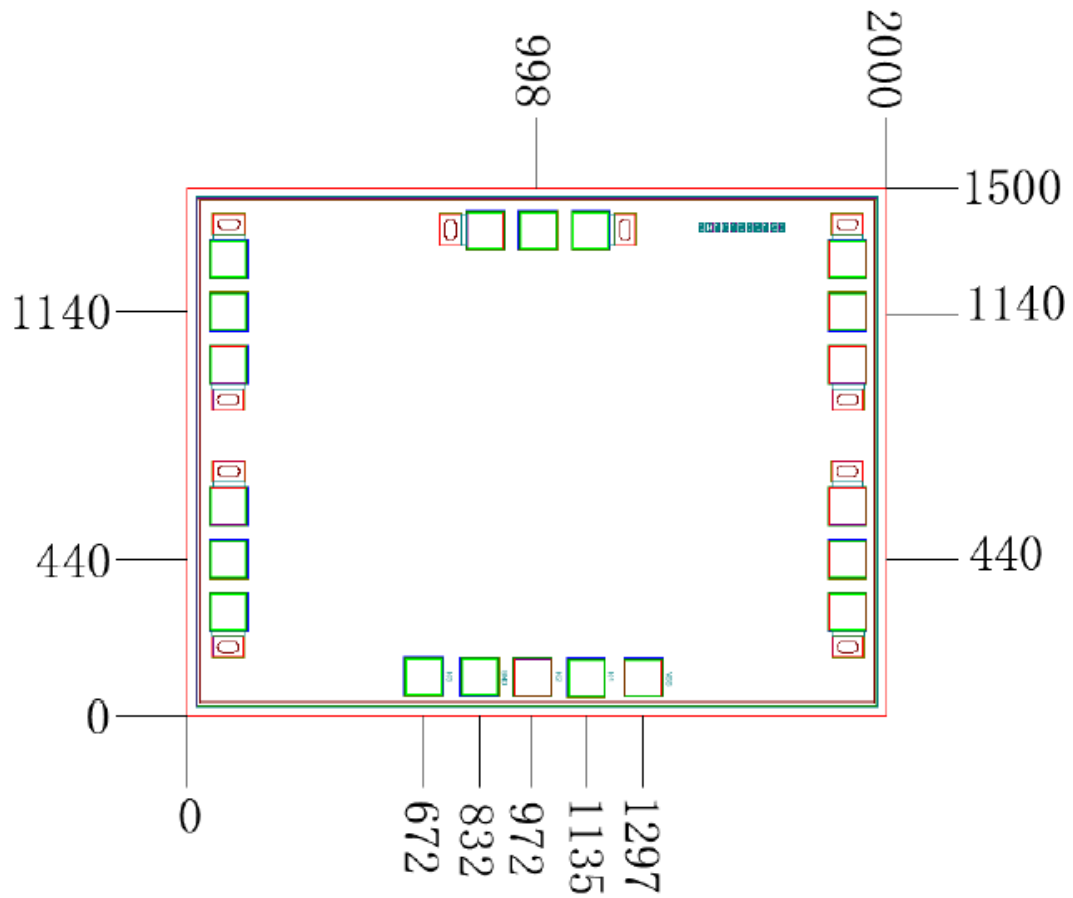
**Electrical Characteristics (Ta = 25°C)**

| Symbol       | Parameter                      | Value |         |     | Unit |
|--------------|--------------------------------|-------|---------|-----|------|
|              |                                | Min   | Typical | Max |      |
| VSWRin       | Input standing wave            | -     | 1.5     | 1.7 | -    |
| VSWRout(On)  | ON state output standing wave  | -     | 1.4     | 1.6 | -    |
| VSWRout(Off) | OFF state output standing wave | -     | 1.2     | 1.4 | -    |
| IL           | Insertion Loss                 | -     | 1.7     | 2   | dB   |
| ISO          | Isolation                      | 45    | 50      | -   | dB   |

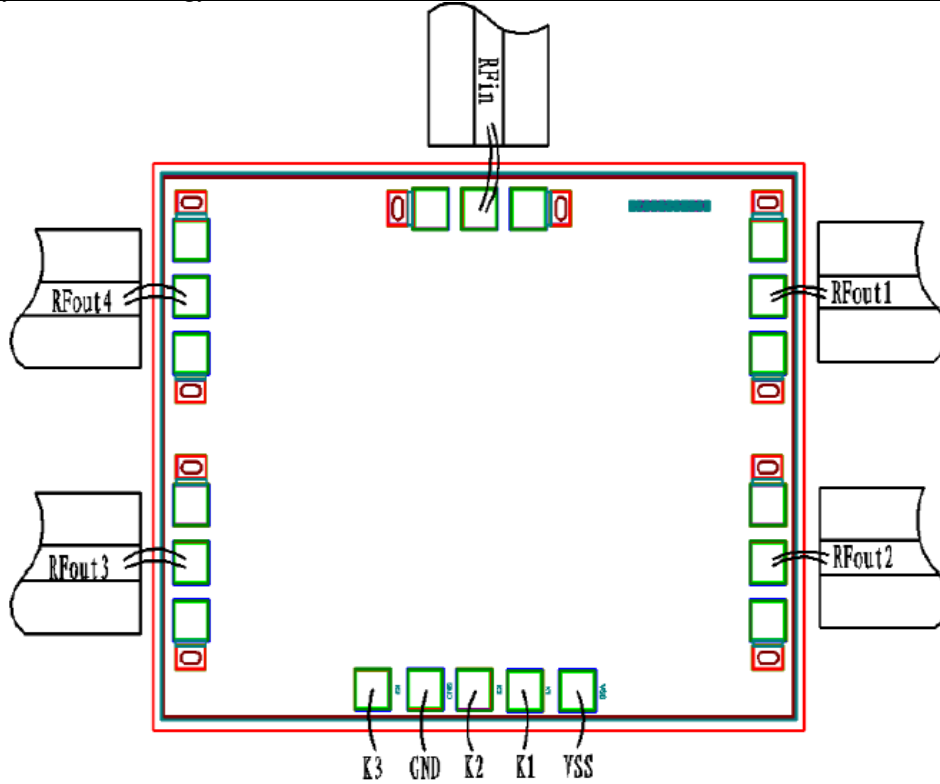
## Typical Performance



**Chip Dimensions (Unit :  $\mu\text{m}$ )**



**Chip Layout Diagram**



**Pad Definition**

| No. | Symbol | Function Description   | Dimension   |
|-----|--------|--|-------------|
| 1   | RFin   | RF signal input port, external connect to 50Ω system, no need DC blocking capacitor    | 100μm*100μm |
| 2   | RFout1 | RF signal output port 1, external connect to 50Ω system, no need DC blocking capacitor | 100μm*100μm |
| 3   | RFout2 | RF signal output port 2, external connect to 50Ω system, no need DC blocking capacitor | 100μm*100μm |
| 4   | RFout3 | RF signal output port 3, external connect to 50Ω system, no need DC blocking capacitor | 100μm*100μm |
| 5   | RFout4 | RF signal output port 4, external connect to 50Ω system, no need DC blocking capacitor | 100μm*100μm |
| 6   | K1     | Supply voltage control port, see Truth Table for control logic                         | 100μm*100μm |
| 7   | K2     | Supply voltage control port, see Truth Table for control logic                         | 100μm*100μm |
| 8   | K3     | Supply voltage control port, see Truth Table for control logic                         | 100μm*100μm |
| 9   | VSS    | TTL driver circuit supply port, connect to -5V supply                                  | 100μm*100μm |
| 10  | GND    | TTL driver circuit ground port, grounded or floating when using                        | 100μm*100μm |

**Truth Table**

| Function      | VSS | K1 | K2 | K3 |
|---------------|-----|----|----|----|
| RFin – Rfout1 | -5V | 0V | 0V | 0V |
| RFin – Rfout2 |     | 5V | 0V | 0V |
| RFin – Rfout3 |     | 0V | 5V | 0V |
| RFin – Rfout4 |     | 5V | 5V | 0V |
| OFF           |     | -  | -  | 5V |

Please see Appendix A for details.